2SK3539

Silicon N-channel MOSFET

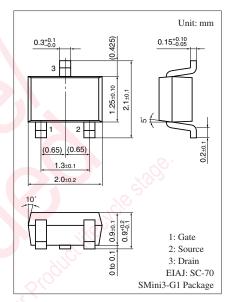
For switching

■ Features

- High-speed switching
- Wide frequency band
- Gate protection diode built-in

■ Absolute Maximum Ratings $T_a = 25$ °C

Symbol	Rating	Unit	
V _{DS}	50	V	
V_{GSO}	±7	V	
I_D	100	mA	
I_{DP}	200	mA	
P_{D}	150	mW	
T _{ch}	150	°C	
T _{stg}	-55 to +150	°C	
	V_{DS} V_{GSO} I_{D} I_{DP} P_{D} T_{ch}	$\begin{array}{c cccc} V_{DS} & 50 \\ V_{GSO} & \pm 7 \\ I_{D} & 100 \\ I_{DP} & 200 \\ P_{D} & 150 \\ T_{ch} & 150 \\ \end{array}$	

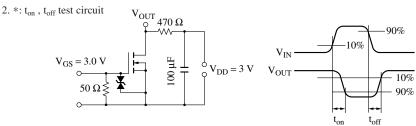


Marking Symbol: 5F

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

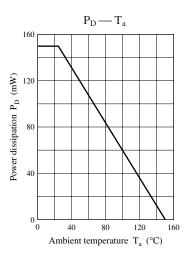
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	$V_{\rm DSS}$	$I_D = 10 \ \mu A, \ V_{GS} = 0$	50	9/0	0.,,	V
Drain-source cutoff current	I_{DSS}	$V_{DS} = 50 \text{ V}, V_{GS} = 0$	NI.	· VIC	1.0	μΑ
Gate-Source cutoff current	I_{GSS}	$V_{GS} = \pm 7 \text{ V}, V_{DS} = 0$	<i>10</i> 0 (80,	±5.0	μΑ
Gate threshold voltage	V_{th}	$I_D = 1.0 \mu\text{A}, V_{DS} = 3 \text{V}$	0.9	1.2	1.5	V
Drain-source ON resistance	R _{DS(on)}	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	7.6	8	15	Ω
	•	$I_D = 10 \text{ mA}, V_{GS} = 4.0 \text{ V}$		6	12	
Forward transfer admitance	$ Y_{fs} $	$I_D = 10 \text{ mA}, V_{DS} = 3 \text{ V}, f = 1 \text{ kHz}$	20	60		mS
Short-circuit forward transfer	C _{iss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		12		pF
capacitance (Common source)		ish who				
Short-circuit output capacitance (Common source)	C_{oss}	2, 1/1/20		7		pF
Reverse transfer capacitance (Common source)	C_{rss}	as with		3		pF
Turn-on time *	t _{on}	$V_{DD} = 3 \text{ V}, V_{GS} = 0 \text{ V} \text{ to } 3 \text{ V}, R_L = 470 \Omega$		200		ns
Turn-off time *	$t_{\rm off}$	$V_{DD} = 3 \text{ V}, V_{GS} = 3 \text{ V to } 0 \text{ V}, R_L = 470 \Omega$		200		ns

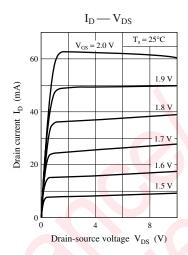
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

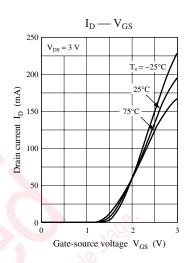


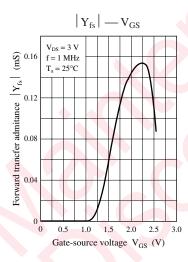
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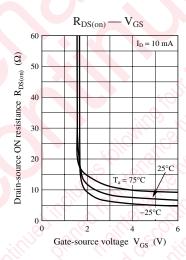
Panasonic

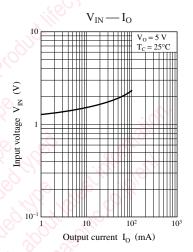












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